

Electrical and Computer Engineering Department  
 University of Puerto Rico - Mayaguez, P.R.  
 Electronics II - INEL 4202 - Fall 2001 - Prof. Manuel Toledo  
 Solutions to Exam 3

1. For the 741 circuit estimate the d.c. operating point current in the collector of  $Q_1$  in the event that  $\pm 10V$  supplies are used. Also, find the input resistance seen by a differential source connected between the bases of  $Q_1$  and  $Q_2$ . (15 pts. each)

ANSWER:

$$I_{ref} = \frac{20V - 1.4V}{39k\Omega} = 477\mu A$$

$$I_{C10} = \frac{V_T}{R_M} \ln \left( \frac{I_{ref}}{I_{C10}} \right) = 5\mu A \ln \left( \frac{477\mu A}{I_{C10}} \right)$$

Let an initial guess for  $I_{C10}$  be  $100\mu A$ . After a few iterations, above equation converges to  $I_{C10} = 16.8\mu A$ . As we saw in our lectures,

$$I_{C1} \approx \frac{I_{C10}}{2} = 8.4\mu A$$

From lectures,

$$R_{in} = 4r_\pi = 4 \times \beta \times \frac{V_T}{I_{C1}} = 4 \times 200 \times \frac{25mV}{8.4\mu A} = 2.4M\Omega$$

2. Consider the design of the second stage of the 741. What value of  $R_9$  would be needed to reduce the current  $I_{C16}$  to  $9.5\mu A$ ? Assume that the circuit is using  $\pm 15V$  power supplies, and that the  $I_{C13B} = 550\mu A$ . (20 pts.)

ANSWER:

$$I_{C16} \approx I_{E16} = I_{R_9} + I_{B17} = \frac{V_{E16}}{R_9} + I_{B17}$$

$$I_{B17} = \frac{I_{E17}}{\beta_N + 1} = \frac{550\mu A}{201} = 2.75\mu A$$

$$v_{BE17} = V_T \ln \left( \frac{I_{C17}}{I_S} \right) = 25mV \ln \left( \frac{550\mu A}{10^{-14} A} \right) = 0.62V$$

$$V_{E16} = v_{BE17} + I_{E17} \times 100\Omega = 0.675V$$

$$9.5\mu A = \frac{0.675V}{R_9} + 2.75\mu A$$

Finally,

$$R_9 = \frac{0.675V}{9.5\mu A - 2.75\mu A} = 100k\Omega$$

3. (a) Utilizing a reference current of  $100\mu A$ , design a Widlar current source to provide an output current of  $10\mu A$ . Let the BJTs have  $v_{BE} = 0.7V$  at 1-mA current, and assume  $\beta$  to be very high. (20 pts)

ANSWER:

$$R_M = \frac{V_T}{I_O} \ln \left( \frac{I_{ref}}{I_O} \right) = \frac{25mV}{10\mu A} \ln \left( \frac{100\mu A}{10\mu A} \right) = 5756\Omega$$

- (b) For the source designed in (a), assume  $\beta = 200$  and  $V_A = 100V$ . Find the value of the output resistance, and find the change in output current corresponding to a 5V change in output voltage. (15 pts each)

ANSWER:

$$r_O = \frac{V_A}{I_O} = \frac{100V}{10\mu A} = 10M\Omega$$

$$R_O = r_O (1 + g_m R_M) = 10M\Omega \left( 1 + \frac{10\mu A}{25mV} \times 5756\Omega \right) = 33M\Omega$$

$$\Delta I_O = \frac{5V}{33M\Omega} = 0.15\mu A$$

or about 1.5%.

NOTE: A COPY OF FIGURE 10.1 FROM SEDRA AND SMITH WAS INCLUDED WITH THE EXAM